

# SiC – photodiode

JEC 0,1 IS  
JEC 0,1 ISZ



- characteristics :**
- ◆ spectral range 210 ... 380 nm
  - ◆ active area 0,055 mm<sup>2</sup>
  - ◆ high UV-responsivity 0,13 A/W
  - ◆ TO 18-package
  - ◆ photodiode isolated to package
  - ◆ components are in conformity with RoHS and WEEE

- applications :**
- ◆ UV-measurements only
  - ◆ UV-source control
  - ◆ flame detection

## maximum ratings :

reverse voltage 20 V  
operating temperature range -25 °C ... 70 °C  
storage temperature range 0 °C ... 100 °C  
soldering temperature (3s) 260 °C

## technical data :

test conditions, as not otherwise specified:  $\gamma_a = 25 \text{ °C}$ ,  $V_R = 0V$

parameters	test conditions	min.	typ.	max.	unit
active area			0,25 x 0,25		mm <sup>2</sup>
spectral range		210		380	nm
maximum of spectral responsivity	$\lambda_{\max} = 275 \text{ nm}$		0,13		A/W
absolute spectral responsivity	$\lambda = 254 \text{ nm}$		0,11		A/W
dark current $I_R$	$V_R = 1 \text{ V}$		1		fA
short current (sunlight)	bright sun cloudy		50 20		nA
capacitance			21		pF



**Electro Optical Components, Inc.**

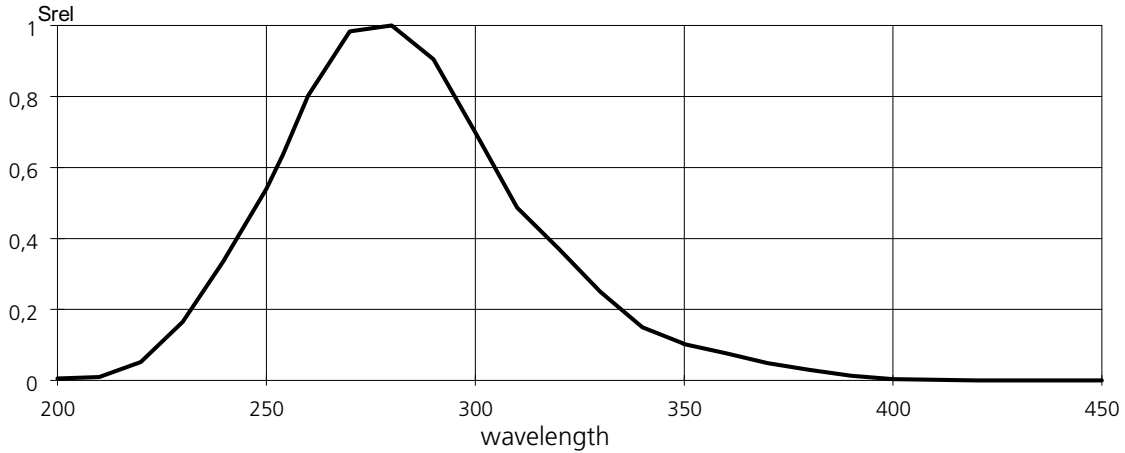
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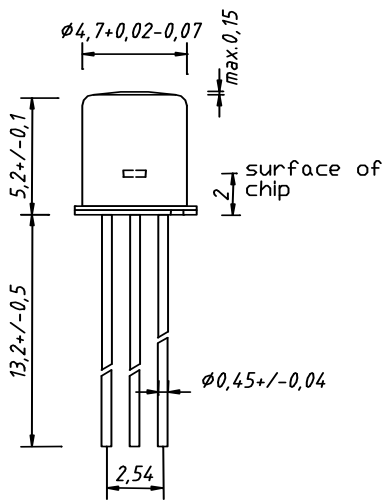
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## relative spectral responsivity

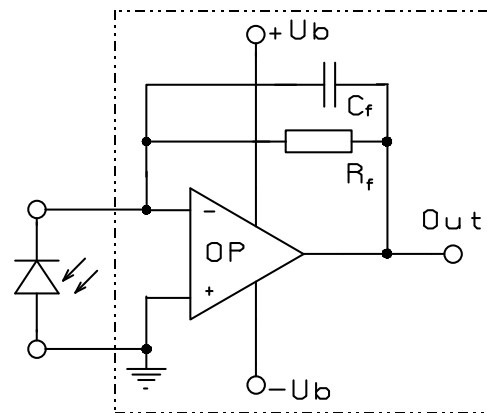
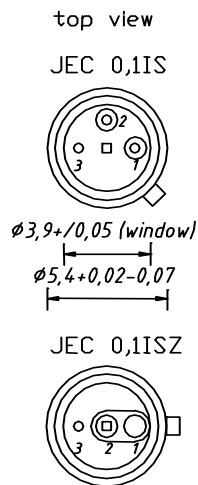


## package dimensions



- 1 cathode
- 2 anode
- 3 case

## application example



The application example shows a typical circuit.  $R_f$  is responsible for the gain of the circuit.  $C_f$  compensates the reverse junction capacitance of the photodiode and input capacitance of the OPV. The exact value of  $C_f$  depends on  $R_f$ , used OPV and capacitance of the circuit. A typical value is 1 pF.

The diagram shows dependence of amplitude of the application circuit with OPA 111,  $R_f = 50 \text{ M}\Omega$  and  $C_f = 0.5 \text{ pF}$ .

